

Pb Free Plating Product

HERF1001GA thru HERF1008GA



10.0 Ampere Insulated Dual Common Anode High Efficiency Rectifiers

Features

- ★ Fast switching for high efficiency
- ★ Low forward voltage drop
- ★ High current capability
- ★ Low reverse leakage current
- ★ High surge current capability

Application

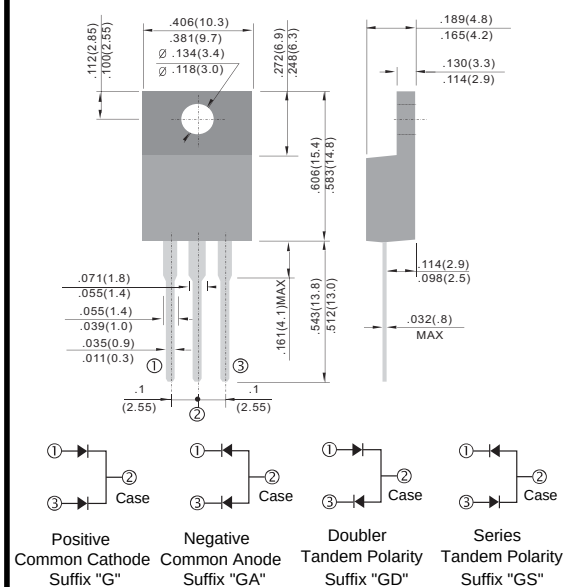
- ★ Automotive Inverters/Solar Inverters
- ★ Plating Power Supply, SMPS and UPS
- ★ Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- ★ Case: Fully Molded Isolated Package TO-220F
- ★ Epoxy: UL 94V-0 rate flame retardant
- ★ Terminals: Solderable per MIL-STD-202 method 208
- ★ Polarity: As marked on diode body
- ★ Mounting position: Any
- ★ Weight: 2.1 gram approxiamtely

ITO-220AB

Unit : inch (mm)

**Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	HERF 1001GA	HERF 1002GA	HERF 1003GA	HERF 1004GA	HERF 1005GA	HERF 1006GA	HERF 1007GA	HERF 1008GA	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current	I _{F(AV)}	10								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	125								A
Maximum Instantaneous Forward Voltage (Note 1) @ 5 A	V _F	1.0				1.3	1.7			V
Maximum DC Reverse Current @ T _A =25 °C at Rated DC Blocking Voltage @ T _A =125 °C	I _R	10 400								uA uA
Maximum Reverse Recovery Time (Note 2)	T _{rr}	50					80			nS
Typical Junction Capacitance (Note 3)	C _j	60					40			pF
Typical Thermal Resistance	R _{θJC}	1.5								°C/W
Operating Temperature Range	T _J	- 65 to + 150								°C
Storage Temperature Range	T _{STG}	- 65 to + 150								°C

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $IRR=0.25\text{A}$

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (HERF1001GA thru HERF1008GA)

FIG. 1- MAXIMUM FORWARD CURRENT DERATING CURVE

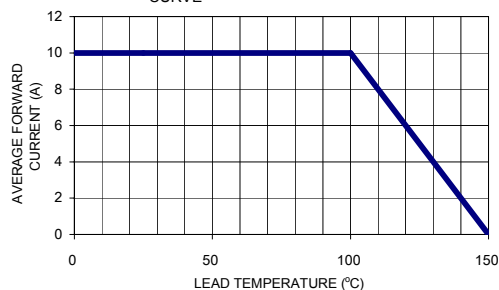


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

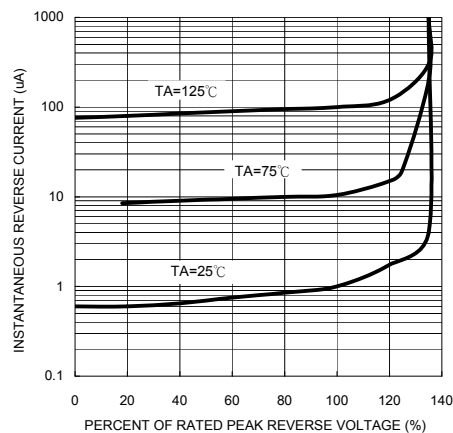


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

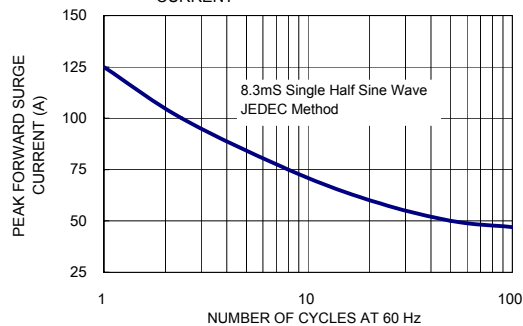


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

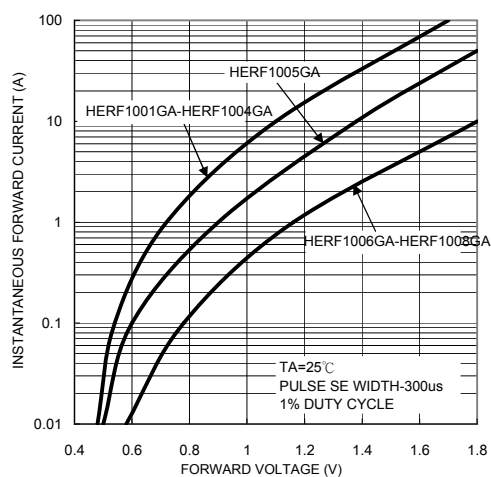


FIG. 4- TYPICAL JUNCTION CAPACITANCE

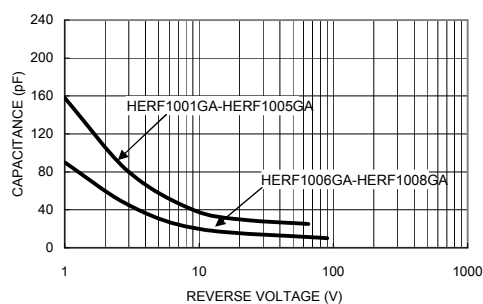


FIG. 6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

